

isc Silicon PNP Power Transistor

2SB826

DESCRIPTION

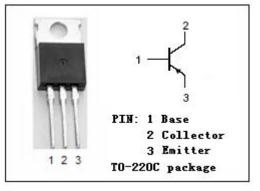
- High Collector Current:: I_C = -12A
- Low Collector Saturation Voltage
- : V_{CE(sat)}= -0.5V(Max)@I_C= -6A
- Wide Area of Safe Operation
- Complement to Type 2SD1062
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

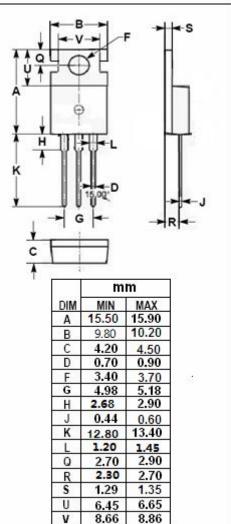


• Designed for relay drivers, high-speed inverters, converters, and other gereral high-current switching applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

| SYMBOL | PARAMETER | VALUE | UNIT |
|------------------|--|-------|------|
| V _{CBO} | Collector-Base Voltage | V | |
| V _{CEO} | Collector-Emitter Voltage | -50 | V |
| V _{EBO} | Emitter-Base Voltage | -6 | V |
| lc | Collector Current-Continuous | -12 | A |
| Ісм | Collector Current-Peak | -15 | A |
| Pc | Total Power Dissipation @ T _c =25℃ | 40 | W |
| TJ | Junction Temperature | 150 | °C |
| T _{stg} | Storage Temperature Range -55~150 | | °C |







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ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP. | МАХ | UNIT |
|----------------------|--------------------------------------|--|-----|------|------|------|
| V _{(BR)CEO} | Collector-Emitter Breakdown Voltage | I _C = -1mA ; R _{BE} = ∞ | -50 | | | V |
| V _{(BR)CBO} | Collector-Base Breakdown Voltage | I _C = -1mA ; I _E = 0 | -60 | | | V |
| V _{(BR)EBO} | Emitter-Base Breakdown Voltage | I _E = -1mA ; I _C = 0 | -6 | | | V |
| V _{CE(sat)} | Collector-Emitter Saturation Voltage | I _C = -6A; I _B = -0.3A | | | -0.5 | V |
| I _{CBO} | Collector Cutoff Current | V_{CB} = -40V; I _E = 0 | | | -0.1 | mA |
| I _{EBO} | Emitter Cutoff Current | V _{EB} = -4V; I _C = 0 | | | -0.1 | mA |
| h _{FE-1} | DC Current Gain | I _C = -1A; V _{CE} = -2V | 70 | | 280 | |
| hfe-2 | DC Current Gain | Ic= -5A; Vce= -2V | 30 | | | |

h_{FE-1} Classifications

| Q | R | s |
|--------|---------|---------|
| 70-140 | 100-200 | 140-280 |

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